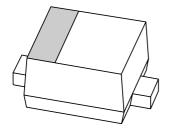
## **DISCRETE SEMICONDUCTORS**

## DATA SHEET



## PMEG2010AEB

20 V, 1 A ultra low V<sub>F</sub> MEGA Schottky barrier rectifier in SOD523 package

**Product specification** 

2003 Dec 03





## 20 V, 1 A ultra low V<sub>F</sub> MEGA Schottky barrier rectifier in SOD523 package

### PMEG2010AEB

#### **FEATURES**

Forward current: 1.0 AReverse voltage: 20 VUltra low forward voltage

· Ultra small SMD package.

#### **APPLICATIONS**

Low voltage rectification

• High efficiency DC/DC conversion

· Voltage clamping

• Inverse-polarity protection

• Low power consumption applications.

#### **DESCRIPTION**

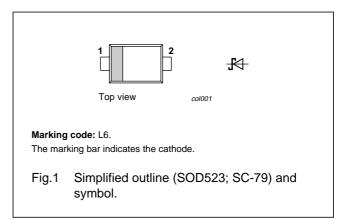
Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD523 (SC-79) ultra small plastic SMD package.

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	MAX.	UNIT
I <sub>F</sub>	forward current	1	Α
$V_R$	reverse voltage	20	٧

#### **PINNING**

PIN	DESCRIPTION	
1	cathode	
2	anode	



#### **ORDERING INFORMATION**

TYPE NUMBER		PACKAGE			
I TPE NUMBER	NAME	DESCRIPTION	VERSION		
PMEG2010AEB	_	plastic surface mounted package; 2 leads	SOD523		

#### **RELATED PRODUCTS**

TYPE	DESCRIPTION	FEATURE
PMEG2005EB	0.5 A; 20 V very low V <sub>F</sub> MEGA Schottky rectifier	Lower I <sub>R</sub> in same package
PMEG2010EA	1 A; 20 V very low V <sub>F</sub> MEGA Schottky rectifier	Lower forward current, lower I <sub>R</sub> SOD323 (SC76)

## 20 V, 1 A ultra low V<sub>F</sub> MEGA Schottky barrier rectifier in SOD523 package

### PMEG2010AEB

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>R</sub>	continuous reverse voltage		_	20	V
I <sub>F</sub>	continuous forward current	T <sub>s</sub> ≤ 55 °C	_	1.0	А
I <sub>FRM</sub>	repetitive peak forward current	$t_p \le 1 \text{ ms}; \ \delta \le 0.5$	_	3.5	Α
I <sub>FSM</sub>	non-repetitive peak forward current	t = 8 ms square wave	_	6	Α
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	note 1	_	150	°C
T <sub>amb</sub>	operating ambient temperature	note 1	-65	+150	°C

#### Note

 For Schottky barrier rectifiers, thermal run-away has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses. Nomograms for determination of the reverse power losses P<sub>R</sub> and I<sub>F(AV)</sub> rating will be available on request.

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air; notes 1 and 2	400	K/W
R <sub>th(j-s)</sub>	thermal resistance from junction to soldering point	notes 2 and 3	75	K/W

#### **Notes**

- 1. Refer to SOD523 (SC-79) standard mounting conditions.
- For Schottky barrier rectifiers, thermal run-away has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses. Nomograms for determination of the reverse power losses P<sub>R</sub> and I<sub>F(AV)</sub> rating will be available on request.
- 3. Solder point of cathode tab.

# 20 V, 1 A ultra low $V_F$ MEGA Schottky barrier rectifier in SOD523 package

## PMEG2010AEB

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 0.1 mA	30	60	mV
		I <sub>F</sub> = 1 mA	80	110	mV
		I <sub>F</sub> = 10 mA	140	190	mV
		I <sub>F</sub> = 100 mA	230	290	mV
		I <sub>F</sub> = 1000 mA	510	620	mV
I <sub>R</sub>	continuous reverse current	V <sub>R</sub> = 10 V; note 1	0.17	0.6	mA
		V <sub>R</sub> = 20 V; note 1	0.32	1.5	mA
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz	19	25	pF

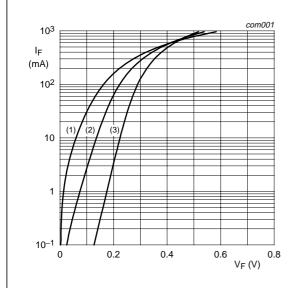
#### Note

1. Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

# 20 V, 1 A ultra low V<sub>F</sub> MEGA Schottky barrier rectifier in SOD523 package

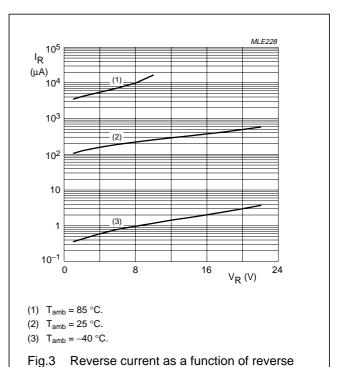
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#### **GRAPHICAL DATA**

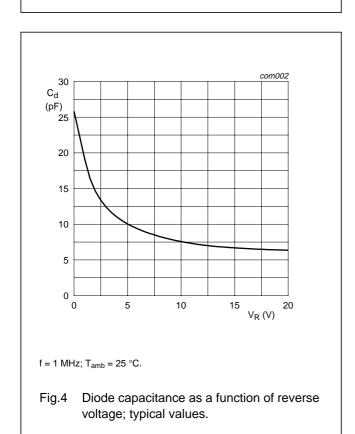


- (1)  $T_{amb} = 85 \, ^{\circ}C$ .
- (2)  $T_{amb} = 25 \, ^{\circ}C$ .
- (3)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig.2 Forward current as a function of forward voltage; typical values.



voltage; typical values.



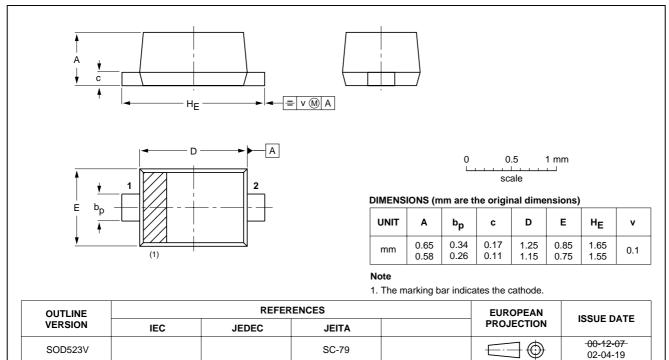
# 20 V, 1 A ultra low V<sub>F</sub> MEGA Schottky barrier rectifier in SOD523 package

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#### **PACKAGE OUTLINE**

### Plastic surface mounted package; 2 leads

SOD523V



## 20 V, 1 A ultra low V<sub>F</sub> MEGA Schottky barrier rectifier in SOD523 package

### PMEG2010AEB

#### **DATA SHEET STATUS**

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification.  Supplementary data will be published at a later date. Philips  Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

#### **Notes**

- Please consult the most recently issued data sheet before initiating or completing a design.
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- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

#### **DEFINITIONS**

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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#### **Contact information**

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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